

# PJA3415A-AU

## 20V P-Channel Enhancement Mode MOSFET

**Voltage**    **-20 V**    **Current**    **-4.5A**

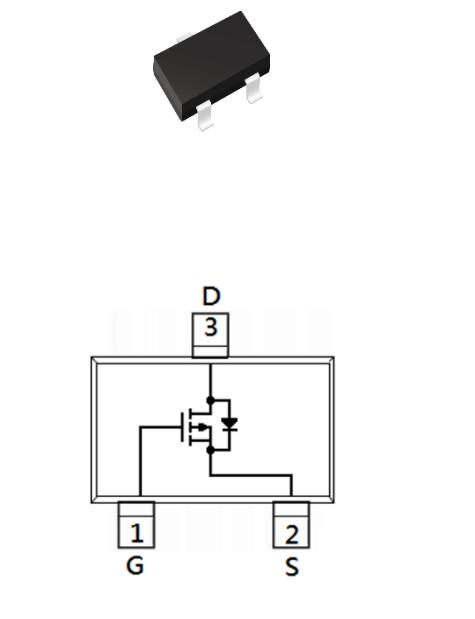
### Features

- $R_{DS(ON)}$ ,  $V_{GS} @ -4.5V$ ,  $I_D @ -4.5A < 48m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS} @ -2.5V$ ,  $I_D @ -3A < 60m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS} @ -1.8V$ ,  $I_D @ -1.5A < 88m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : SOT-23 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.0003 ounces, 0.0084 grams

SOT-23



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ C$ unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	
Continuous Drain Current <sup>(Note 4)</sup>	$I_D$	-4.5	A
Pulsed Drain Current <sup>(Note 1)</sup>	$I_{DM}$	-18	
Power Dissipation	$P_D$	1.25	W
		10	mW/ $^\circ C$
Operating Junction and Storage Temperature Range	$T_J, T_{STG}$	-55~150	$^\circ C$
Typical Thermal Resistance - Junction to Ambient <sup>(Note 3,4)</sup>	$R_{\theta JA}$	100	$^\circ C/W$

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## Electrical Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=-250\mu\text{A}$	-20	-	-	V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=-250\mu\text{A}$	-0.5	-0.74	-1.3	
Drain-Source On-State Resistance	$R_{\text{DS}(\text{on})}$	$V_{\text{GS}}=-4.5\text{V}, I_{\text{D}}=-4.5\text{A}$	-	40	48	$\text{m}\Omega$
		$V_{\text{GS}}=-2.5\text{V}, I_{\text{D}}=-3\text{A}$	-	50	60	
		$V_{\text{GS}}=-1.8\text{V}, I_{\text{D}}=-1.5\text{A}$	-	75	88	
Zero Gate Voltage Drain Current	$I_{\text{DSS}}$	$V_{\text{DS}}=-16\text{V}, V_{\text{GS}}=0\text{V}$	-	-	-1	$\mu\text{A}$
Gate-Source Leakage Current	$I_{\text{GSS}}$	$V_{\text{GS}}=\pm 12\text{V}, V_{\text{DS}}=0\text{V}$	-	-	$\pm 100$	$\text{nA}$
<b>Dynamic</b> <sup>(Note 5)</sup>						
Total Gate Charge	$Q_g$	$V_{\text{DS}}=-10\text{V}, I_{\text{D}}=-4.5\text{A}, V_{\text{GS}}=-4.5\text{V}$ <sup>(Note 1,2)</sup>	-	10	-	$\text{nC}$
Gate-Source Charge	$Q_{\text{gs}}$		-	1.7	-	
Gate-Drain Charge	$Q_{\text{gd}}$		-	2.4	-	
Input Capacitance	$C_{\text{iss}}$	$V_{\text{DS}}=-10\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHZ}$	-	980	-	$\text{pF}$
Output Capacitance	$C_{\text{oss}}$		-	100	-	
Reverse Transfer Capacitance	$C_{\text{rss}}$		-	81	-	
Turn-On Delay Time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}}=-10\text{V}, I_{\text{D}}=-4.5\text{A}, V_{\text{GS}}=-4.5\text{V}, R_{\text{G}}=6\Omega$ <sup>(Note 1,2)</sup>	-	9.8	-	$\text{ns}$
Turn-On Rise Time	$t_{\text{r}}$		-	54	-	
Turn-Off Delay Time	$t_{\text{d}(\text{off})}$		-	44	-	
Turn-Off Fall Time	$t_{\text{f}}$		-	31	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	$I_s$	---	-	-	-1.5	A
Diode Forward Voltage	$V_{\text{SD}}$	$I_s=1\text{A}, V_{\text{GS}}=0\text{V}$	-	-0.78	-1.2	V

### NOTES :

1. Pulse width $\leq 300\text{us}$ , Duty cycle $\leq 2\%$ .
2. Essentially independent of operating temperature typical characteristics.
3.  $R_{\text{QJA}}$  is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.

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## TYPICAL CHARACTERISTIC CURVES

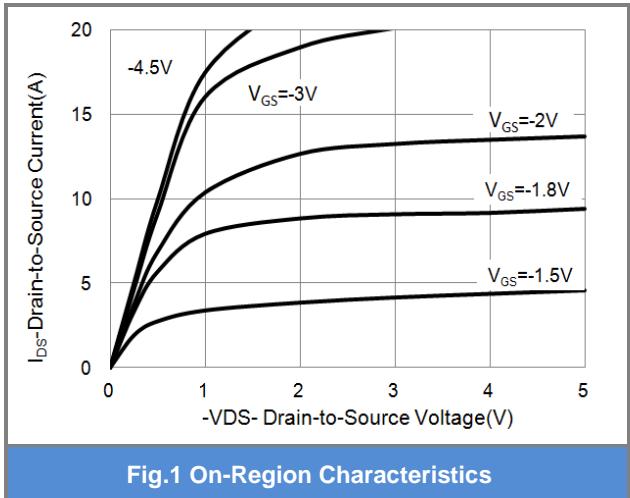


Fig.1 On-Region Characteristics

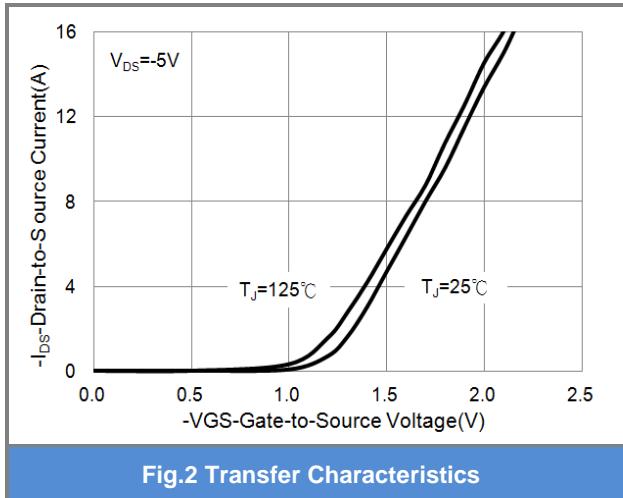


Fig.2 Transfer Characteristics

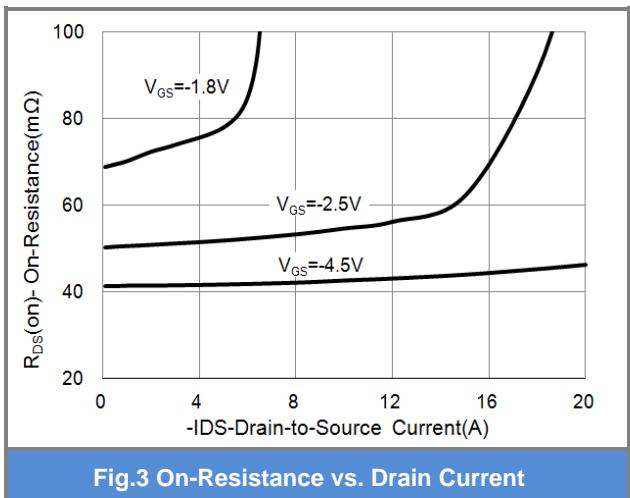


Fig.3 On-Resistance vs. Drain Current

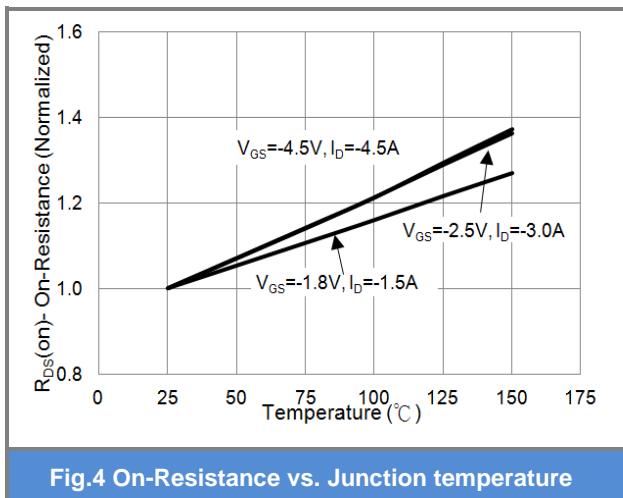


Fig.4 On-Resistance vs. Junction temperature

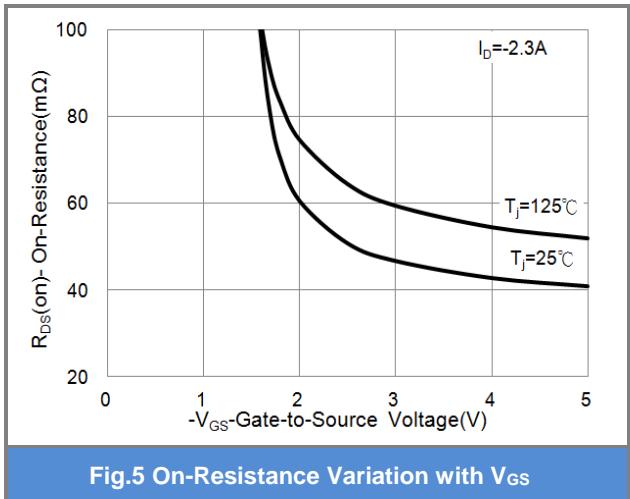


Fig.5 On-Resistance Variation with VGS

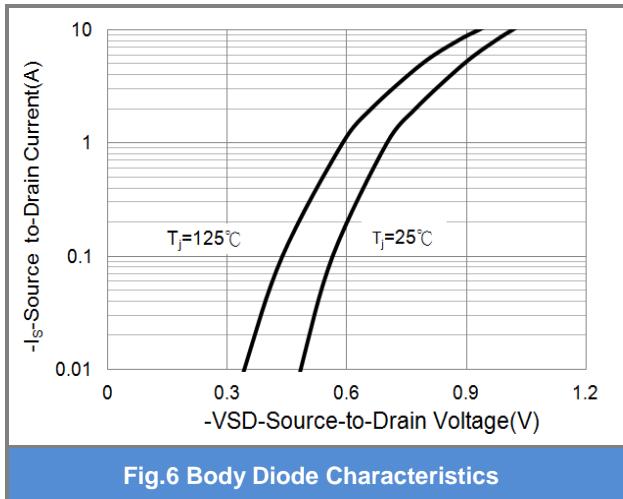
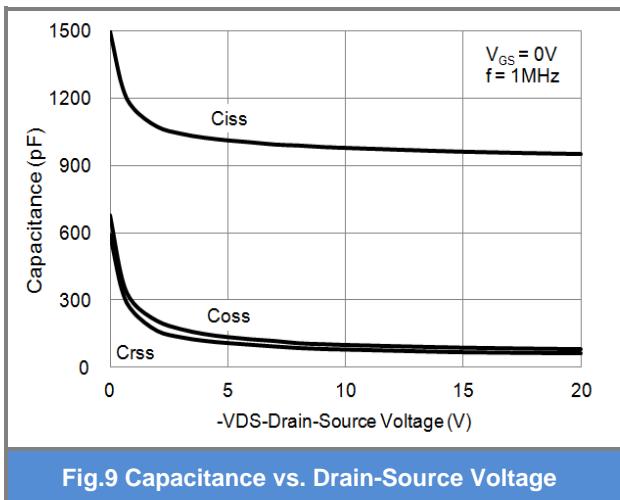
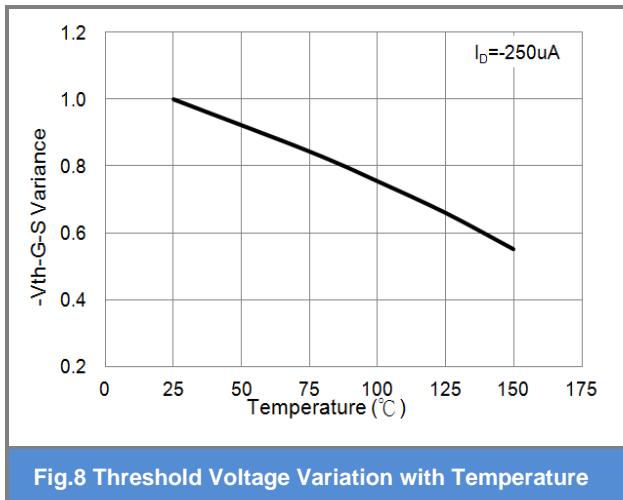
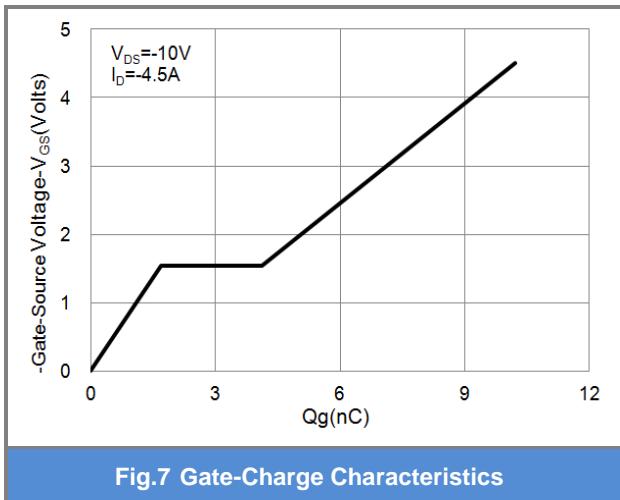


Fig.6 Body Diode Characteristics

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## TYPICAL CHARACTERISTIC CURVES

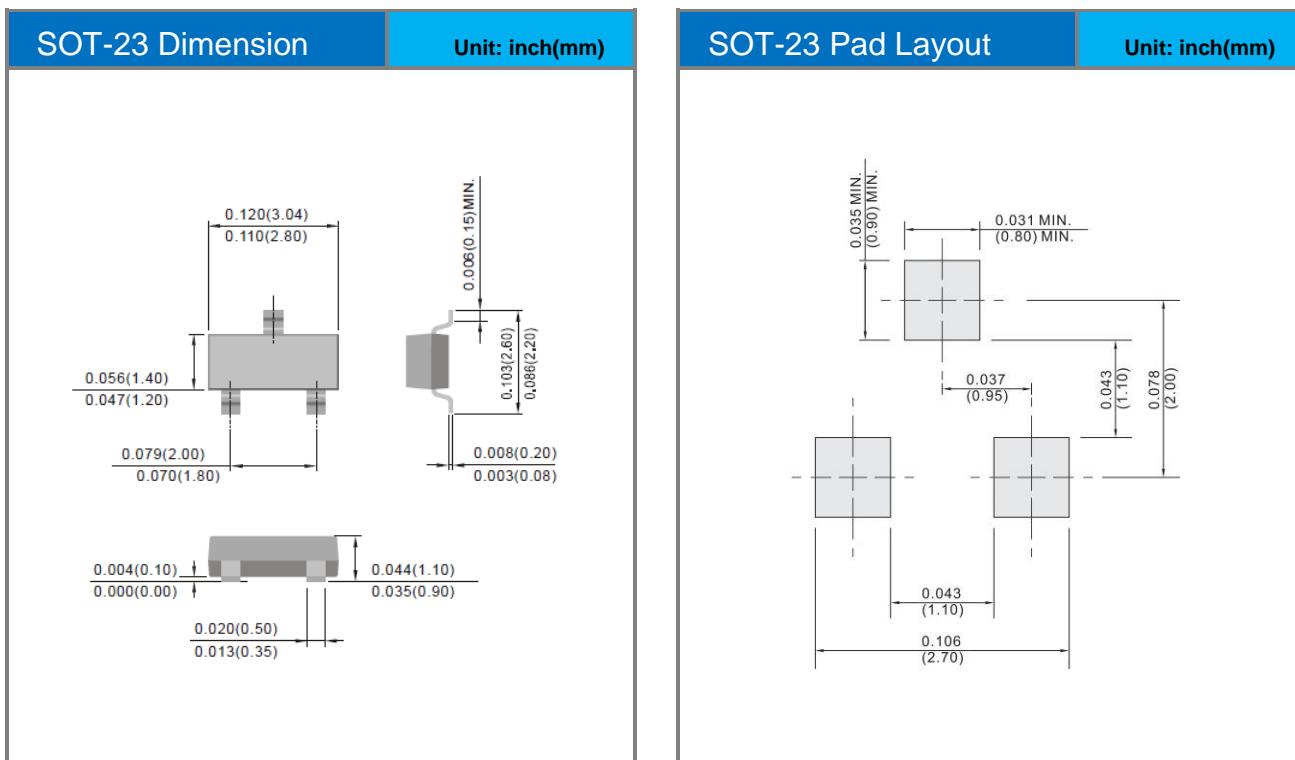


# PJA3415A-AU

## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJA3415A-AU	SOT-23	3K pcs / 7" reel	A5A

## Packaging Information & Mounting Pad Layout



## PJA3415A-AU

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